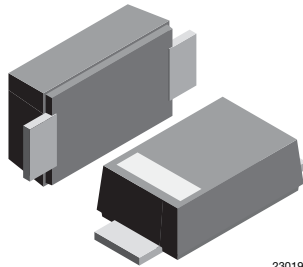
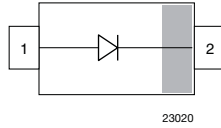


Fast Rectifier Surface Mount

eSMP® Series



SMF (DO-219AB)



23020

DESIGN SUPPORT TOOLS

[click logo to get started](#)


FEATURES

- For surface mounted applications
- Low profile package
- Ideal for automated placement
- Glass passivated
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Wave and reflow solderable
- AEC-Q101 qualified available
- Base P/N-M - halogen-free, RoHS-compliant
- Base P/N-HM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified (available on request)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



MECHANICAL DATA

Case: SMF (DO-219AB)

Polarity: band denotes cathode end

Weight: approx. 15 mg

Packaging codes / options:

18/10K per 13" reel (8 mm tape)

08/3K per 7" reel (8 mm tape)

Circuit configuration: single

PARTS TABLE			
PART	ORDERING CODE	MARKING	REMARKS
RS07B-M	RS07B-M-18 or RS07B-M-08	TB	Tape and reel
RS07D-M	RS07D-M-18 or RS07D-M-08	TD	Tape and reel
RS07G-M	RS07G-M-18 or RS07G-M-08	TG	Tape and reel
RS07J-M	RS07J-M-18 or RS07J-M-08	TJ	Tape and reel
RS07K-M	RS07K-M-18 or RS07K-M-08	TK	Tape and reel

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		RS07B-M	V_{RRM}	100	V
		RS07D-M	V_{RRM}	200	V
		RS07G-M	V_{RRM}	400	V
		RS07J-M	V_{RRM}	600	V
		RS07K-M	V_{RRM}	800	V
Maximum RMS voltage		RS07B-M	V_{RMS}	70	V
		RS07D-M	V_{RMS}	140	V
		RS07G-M	V_{RMS}	280	V
		RS07J-M	V_{RMS}	420	V
		RS07K-M	V_{RMS}	560	V
Maximum DC blocking voltage		RS07B-M	V_{DC}	100	V
		RS07D-M	V_{DC}	200	V
		RS07G-M	V_{DC}	400	V
		RS07J-M	V_{DC}	600	V
		RS07K-M	V_{DC}	800	V
Maximum average forward rectified current	$T_L = 65\text{ }^{\circ}\text{C}$		$I_{F(AV)}$	1.4	A
	$T_A = 45\text{ }^{\circ}\text{C}$		$I_{F(AV)}$	0.5	A
Peak forward surge current 8.3 ms half sine-wave	$T_L = 25\text{ }^{\circ}\text{C}$		I_{FSM}	30	A



THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Thermal resistance junction to lead		R _{thjL}	30	K/W
Thermal resistance junction to ambient air ⁽¹⁾		R _{thjA}	180	K/W
Operating junction and storage temperature range		T _j , T _{stg}	-55 to 150	°C

Note

⁽¹⁾ Mounted on epoxy glass PCB with 3 mm x 3 mm Cu pads (≥ 40 μm thick)

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 0.7 A ⁽¹⁾	RS07B-M	V _F			1.15	V
		RS07D-M	V _F			1.15	V
		RS07G-M	V _F			1.15	V
		RS07J-M	V _F			1.15	V
	I _F = 1 A ⁽¹⁾	RS07K-M	V _F			1.3	V
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C	RS07B-M	I _R			10	μA
		RS07D-M	I _R			10	μA
		RS07G-M	I _R			10	μA
		RS07J-M	I _R			10	μA
		RS07K-M	I _R			2	μA
	T _A = 125 °C	RS07B-M	I _R			50	μA
		RS07D-M	I _R			50	μA
		RS07K-M	I _R			150	μA
Reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	RS07B-M	t _{rr}			150	ns
		RS07D-M	t _{rr}			150	ns
		RS07G-M	t _{rr}			150	ns
		RS07J-M	t _{rr}			250	ns
		RS07K-M	t _{rr}			300	ns
Typical capacitance	4 V, 1 MHz	RS07B-M	C _j		9		pF
		RS07D-M	C _j		9		pF
		RS07G-M	C _j		9		pF
		RS07J-M	C _j		9		pF
		RS07K-M	C _j		4		pF

Note

⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle



TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

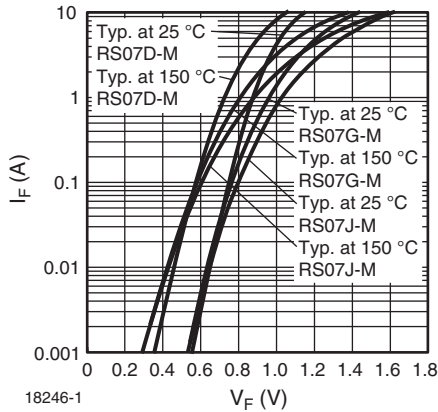


Fig. 1 - Typical Forward Characteristics

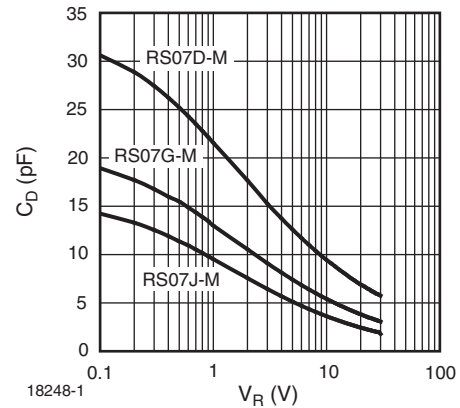


Fig. 4 - Typical Diode Capacitance vs. Reverse Voltage

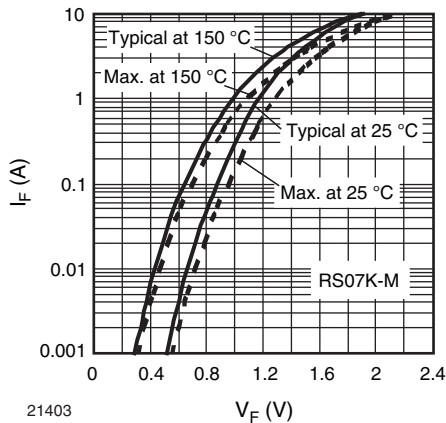


Fig. 2 - Typical Forward Characteristics

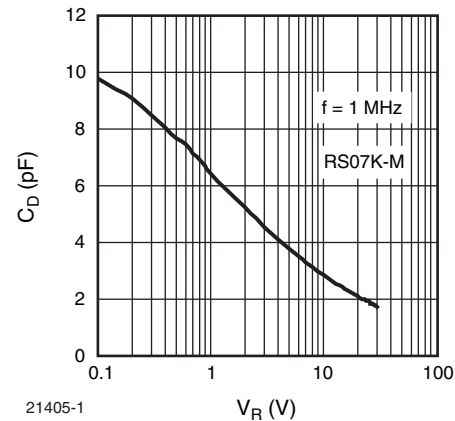


Fig. 5 - Typical Diode Capacitance vs. Reverse Voltage

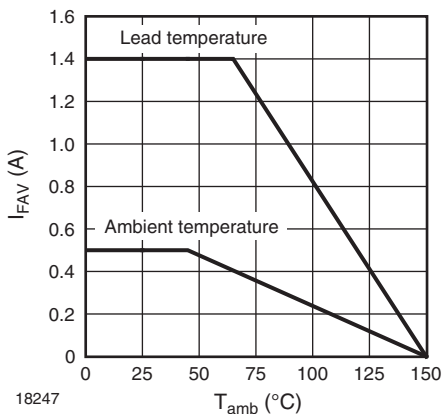


Fig. 3 - Forward Current Derating Curve

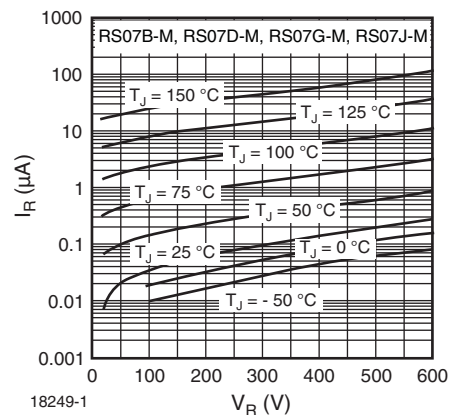


Fig. 6 - Typical Reverse Characteristics